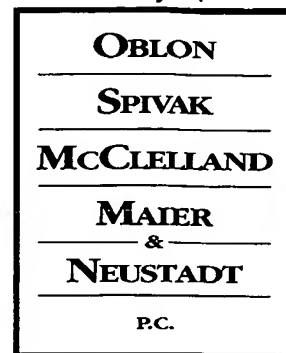




Docket No.: 251390US2



ATTORNEYS AT LAW

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COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

RE: Application Serial No.: 10/814,345

Applicants: Tomoaki SHINO

Filing Date: April 1, 2004

For: SEMICONDUCTOR MEMORY DEVICE FOR
STORING DATA AS STATE OF MAJORITY
CARRIERS ACCUMULATED IN CHANNEL BODY
AND METHOD OF MANUFACTURING THE SAME

Group Art Unit: 2811

Examiner: CRANE, SARA W

SIR:

Attached hereto for filing are the following papers:

REQUEST FOR RECONSIDERATION

Our credit card payment form in the amount of \$0.00 is attached covering any required fees. In the event any variance exists between the amount enclosed and the Patent Office charges for filing the above-noted documents, including any fees required under 37 C.F.R. 1.136 for any necessary Extension of Time to make the filing of the attached documents timely, please charge or credit the difference to our Deposit Account No. 15-0030. Further, if these papers are not considered timely filed, then a petition is hereby made under 37 C.F.R. 1.136 for the necessary extension of time. A duplicate copy of this sheet is enclosed.

Respectfully submitted,

OBLON, SPIVAK, McCLELLAND,
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DOCKET NO: 251390US2

IN THE UNITED STATES PATENT & TRADEMARK OFFICE

IN RE APPLICATION OF :
TOMOAKI SHINO : EXAMINER: CRANE, SARA W
SERIAL NO: 10/814,345 :
FILED: APRIL 1, 2004 : GROUP ART UNIT: 2811
FOR: SEMICONDUCTOR MEMORY :
DEVICE FOR STORING DATA AS
STATE OF MAJORITY CARRIERS
ACCUMULATED IN CHANNEL BODY
AND METHOD OF MANUFACTURING
THE SAME

REQUEST FOR RECONSIDERATION

COMMISSIONER FOR PATENTS
ALEXANDRIA, VIRGINIA 22313

SIR:

In response to the Office Action dated October 6, 2005, Applicant respectfully requests reconsideration of the above-identified application based on the following discussion:

Remarks/Arguments begin on page 2 of this paper.